



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SA1418/2SC3648 — High-Voltage Switching, Preriver Applications

PNP / NPN Epitaxial Planar Silicon Transistor

Applicaitions

- Color TV audio output, inverter

Features

- Adoption of FBET, MBIT processes
- Fast switching speed
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's
- High breakdown voltage and large current capacity

Specifications () : 2SA1418

Absolute Maximum Ratings at Ta=25°C

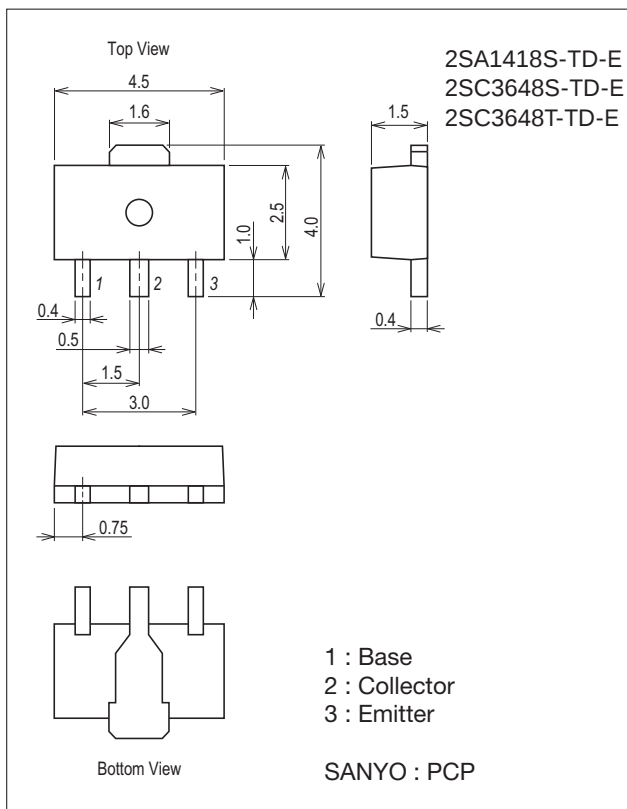
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)180	V
Collector-to-Emitter Voltage	V _{CEO}		(-)160	V
Emitter-to-Base Voltage	V _{EB0}		(-)6	V
Collector Current	I _C		(-)0.7	A
Collector Current (Pulse)	I _{CP}		(-)1.5	A

Continued on next page.

Package Dimensions

unit : mm (typ)

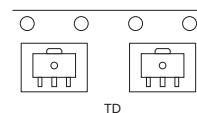
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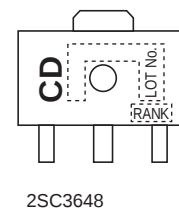
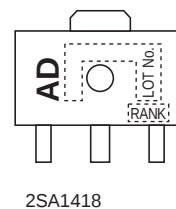
Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

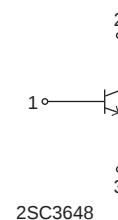
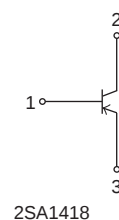
Packing Type: TD



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://www.sanyosemi.com/en/network/>

2SA1418 / 2SC3648

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	P_C		500	mW
		When mounted on ceramic substrate (250mm ² ×0.8mm)	1.3	W
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

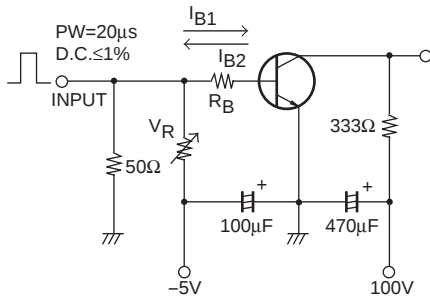
Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)120\text{V}$, $I_E=0\text{A}$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}$, $I_C=0\text{A}$			(-)0.1	μA
DC Current Gain	h_{FE1}	$V_{CE}=(-)5\text{V}$, $I_C=(-)100\text{mA}$	100*		400*	
	h_{FE2}	$V_{CE}=(-)5\text{V}$, $I_C=(-)10\text{mA}$	90			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}$, $I_C=(-)50\text{mA}$		120		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}$, $f=1\text{MHz}$		(11)8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)250\text{mA}$, $I_B=(-)25\text{mA}$		(-0.2)0.12	(-0.5)0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)250\text{mA}$, $I_B=(-)25\text{mA}$		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu\text{A}$, $I_E=0\text{A}$	(-)180			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1\text{mA}$, $R_{BE}=\infty$	(-)160			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu\text{A}$, $I_C=0\text{A}$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		(60)50		ns
Storage Time	t_{stg}			(900)1000		ns
Fall Time	t_f			(60)60		ns

* : The 2SA1418 / 2SC3648 are classified by 100mA h_{FE} as follows :

Rank	R	S	T
h_{FE}	100 to 200	140 to 280	200 to 400

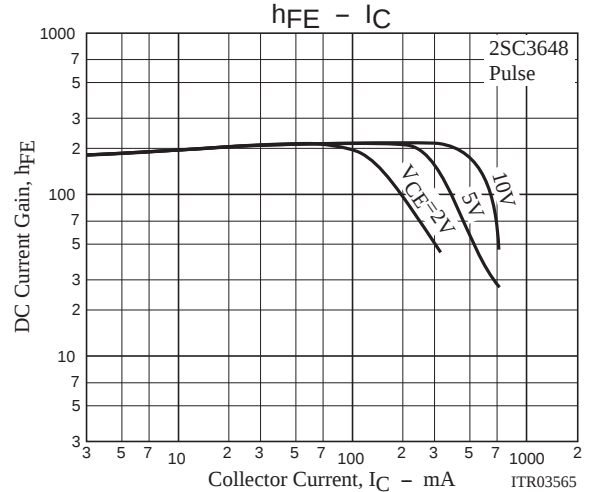
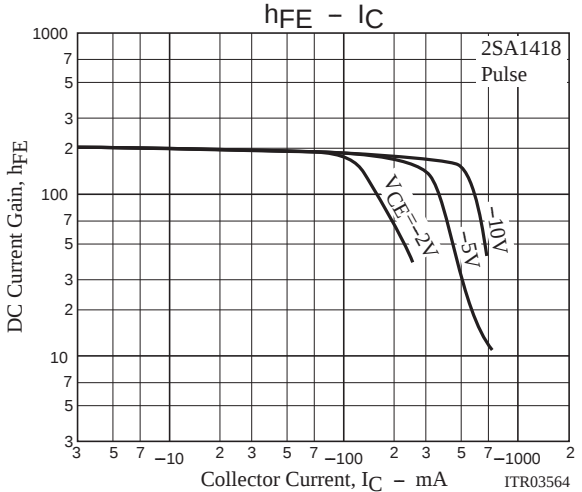
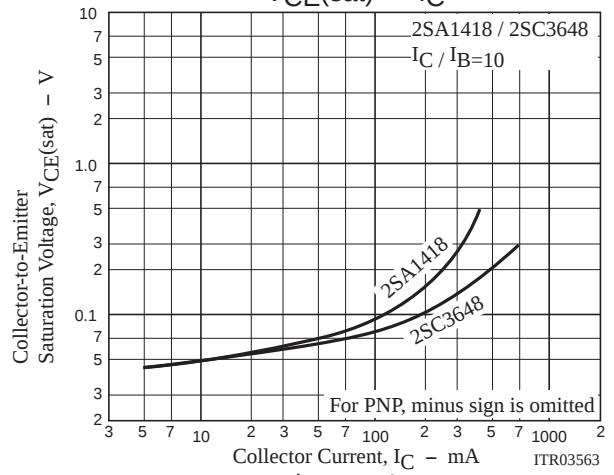
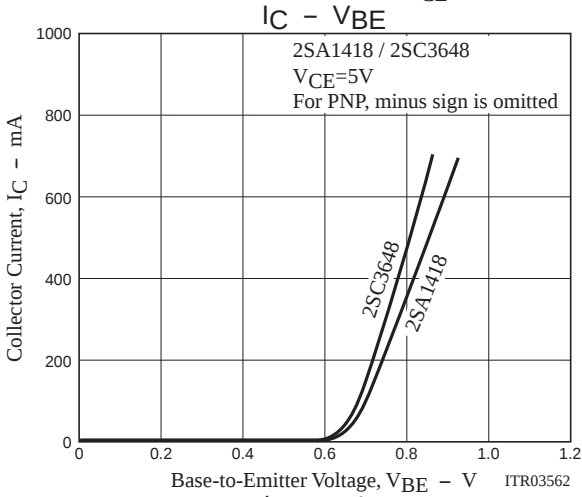
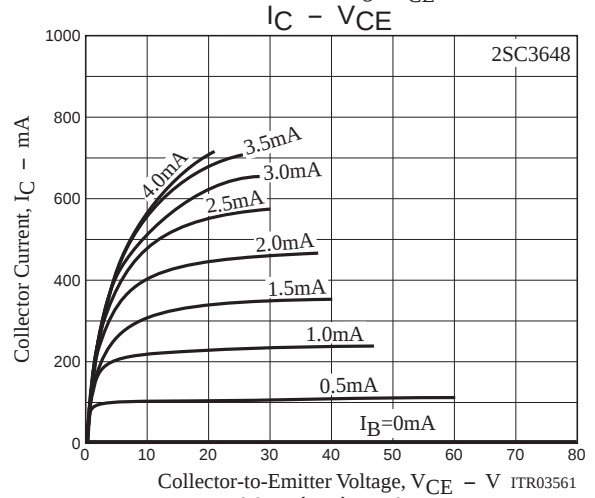
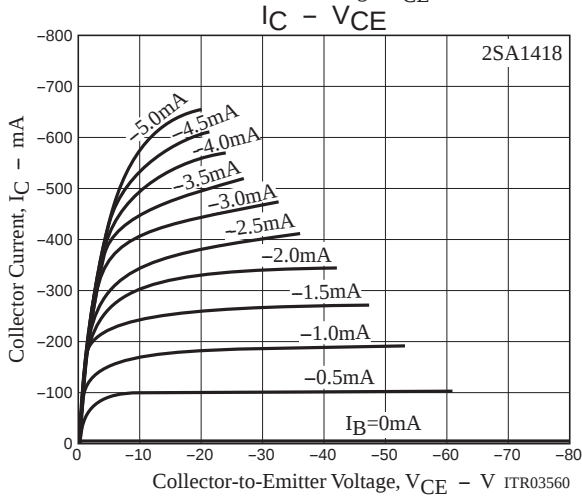
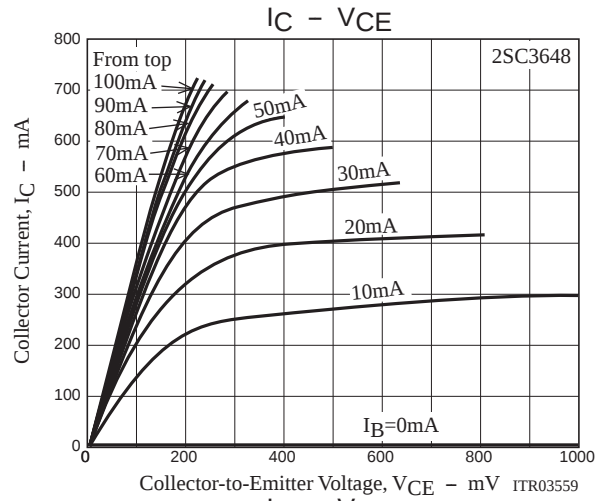
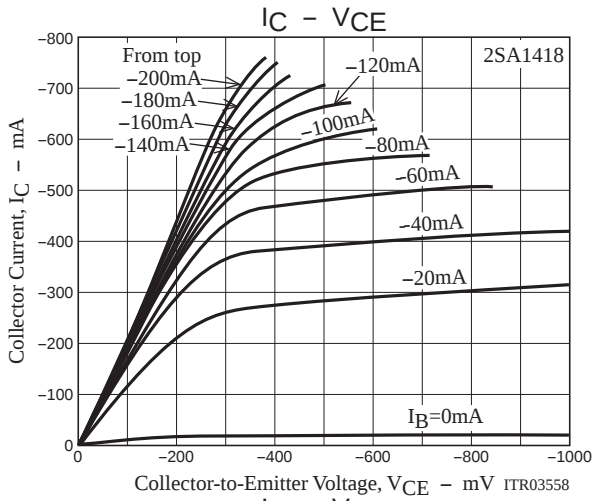
Switching Time Test Circuit

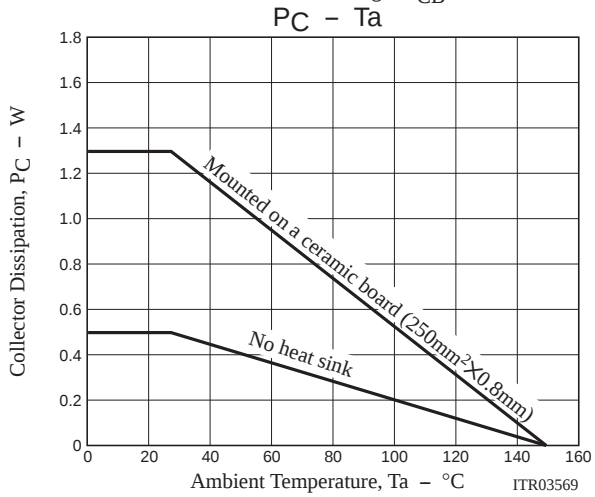
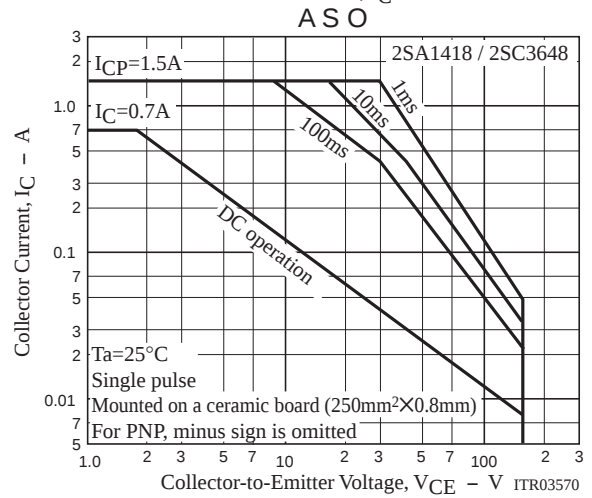
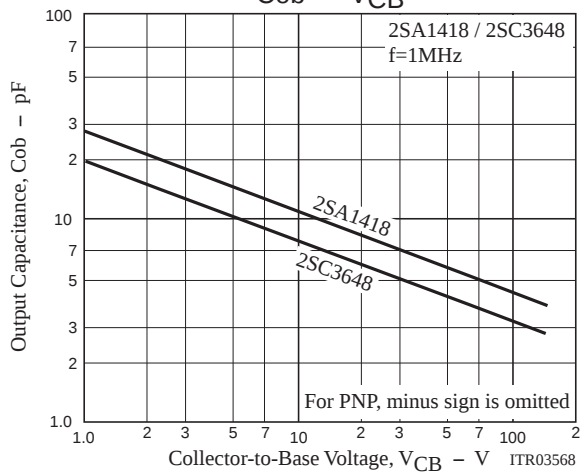
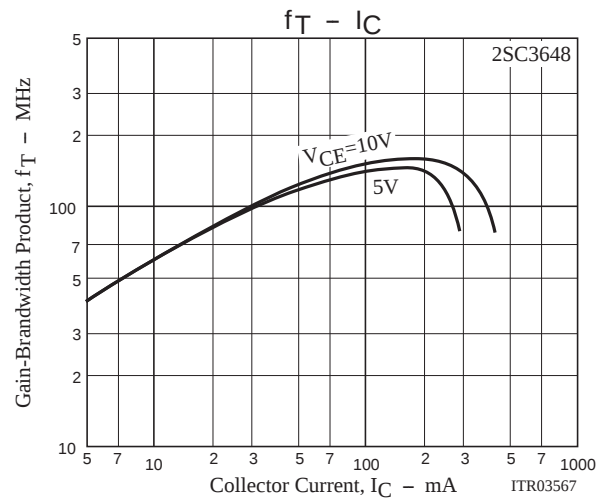
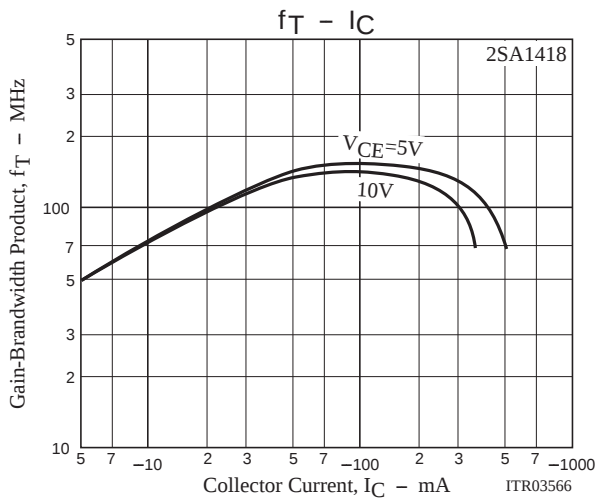


$I_C=20I_{B1}=-20I_{B2}=300\text{mA}$
(For PNP, the polarity is reversed)

Ordering Information

Device	Package	Shipping	memo
2SA1418S-TD-E	PCP	1,000pcs./reel	Pb Free
2SC3648S-TD-E	PCP	1,000pcs./reel	
2SC3648T-TD-E	PCP	1,000pcs./reel	



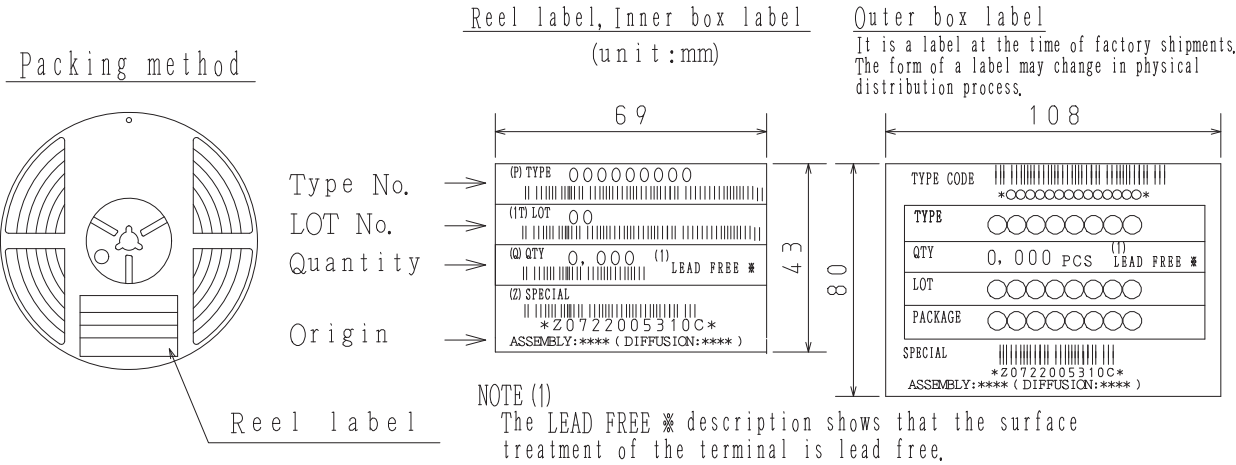


Bag Packing Specification

2SA1418S-TD-E, 2SC3648S-TD-E, 2SC3648T-TD-E

1. Packing Format

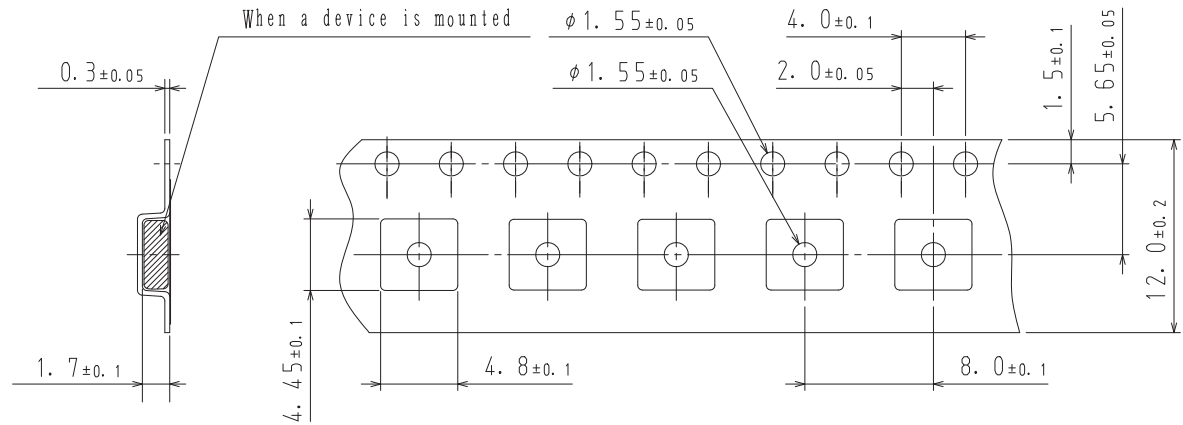
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210



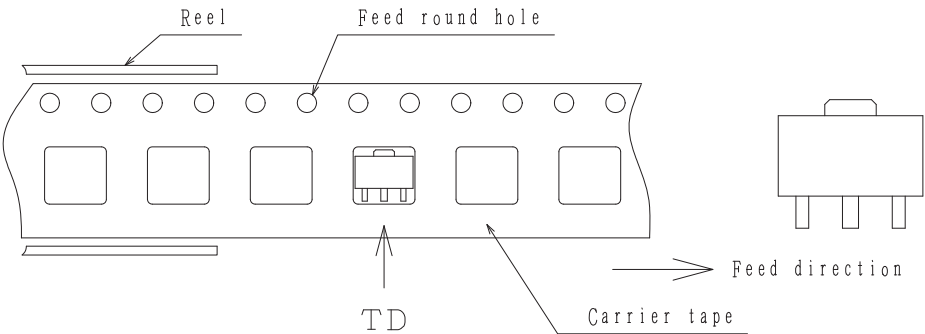
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



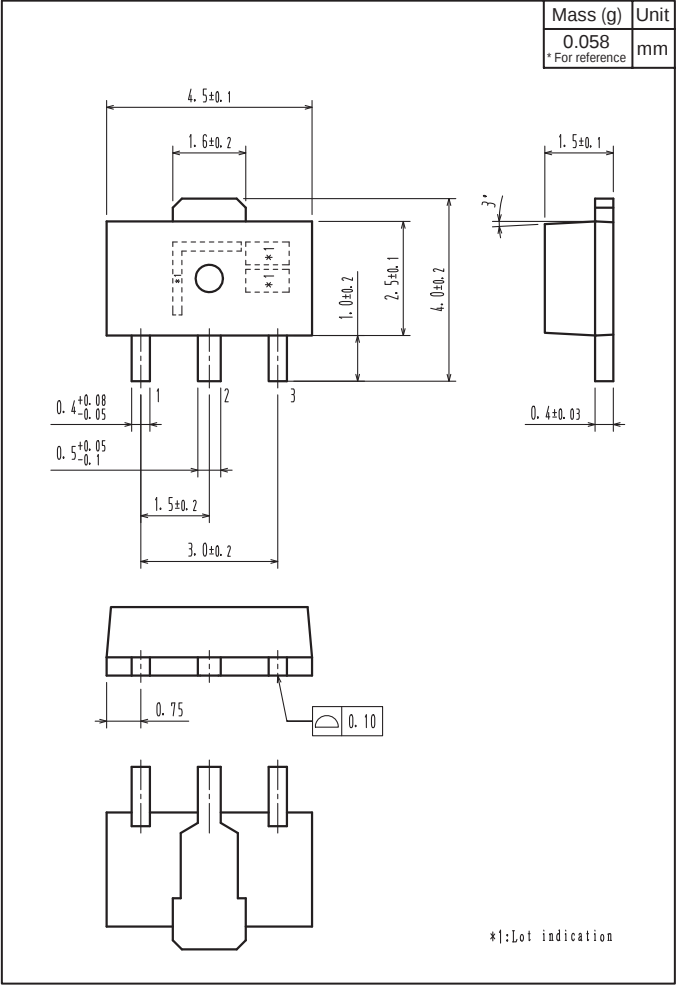
2-2. Device placement direction



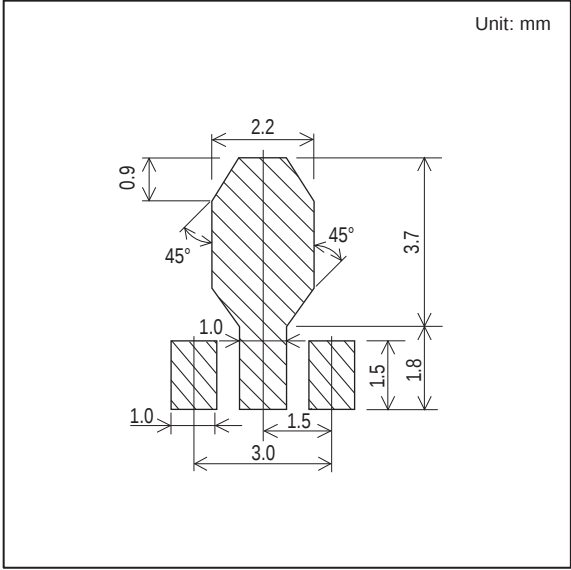
Those with pin 1 index on the feed hole side.....TD

Outline Drawing

2SA1418S-TD-E, 2SC3648S-TD-E, 2SC3648T-TD-E



Land Pattern Example



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